



150V NPN SILICON LOW SATURATION TRANSISTOR IN SOT-23

Features

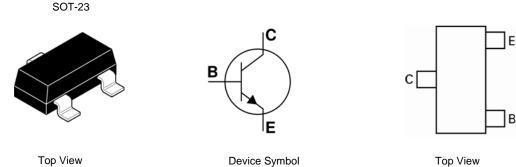
- V_{CEO} = 125V .
- $I_C = 1A$
- 625mW Power dissipation •
- Low Equivalent On Resistance .
- Low Saturation Voltage
- hFE characterised up to 3.0A
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free, "Green" Devices (Note 2)

Mechanical Data

- Case: SOT-23 •
- Case material: "Green" molding Compound. (Note 2)
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.008 grams (Approximate)

Applications

- DC-DC / DC-AC Modules
- Regulator
- LED driver



Pin Configuration

Ordering Information (Note 3)

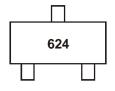
Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT624TA	624	7	8mm embossed	3000 units

Notes:

1. No purposefully added lead. 2. Devices with the PID number starting from PID0155145 are 'Green' products. Halogen and Antimony Free. Diodes Inc.'s "Green" Policy can be found on our website at http://www.diodes.com/

3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



624 = Product Type Marking Code





Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	125	V	
Collector-Emitter Voltage	V _{CEO}	125	V	
Emitter-Base Voltage	V _{EBO}	5	V	
Continuous Collector Current	lc	1	A	
Peak Pulse Current (Note 4)	I _{CM}	3	A	
Base Current	IB	500	mA	

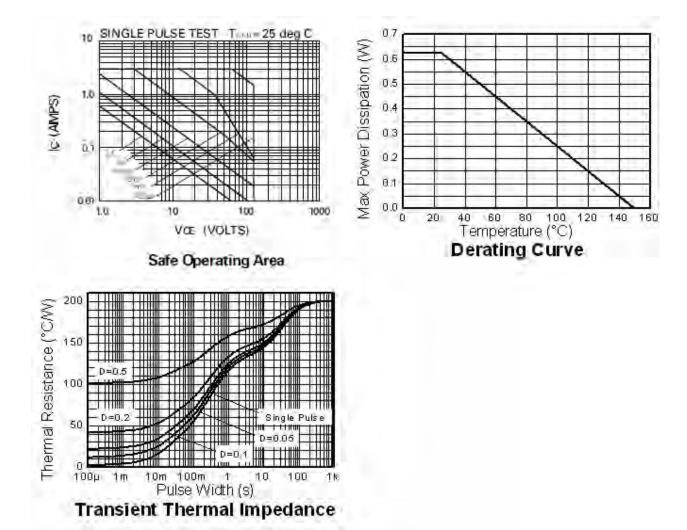
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation at $T_A = 25^{\circ}C$ (Note 5)	PD	625	mW
Thermal Resistance, Junction to Ambient Air (Note 4) @ T _A = 25°C	$R_{\theta JA}$	200	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Notes: 4. Measured under pulsed conditions. Pulse width = 300μ s. Duty cycle $\leq 2\%$.

5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions.

Thermal Characteristics and Derating information







Electrical Characteristics @T_A = 25°C unless otherwise specified

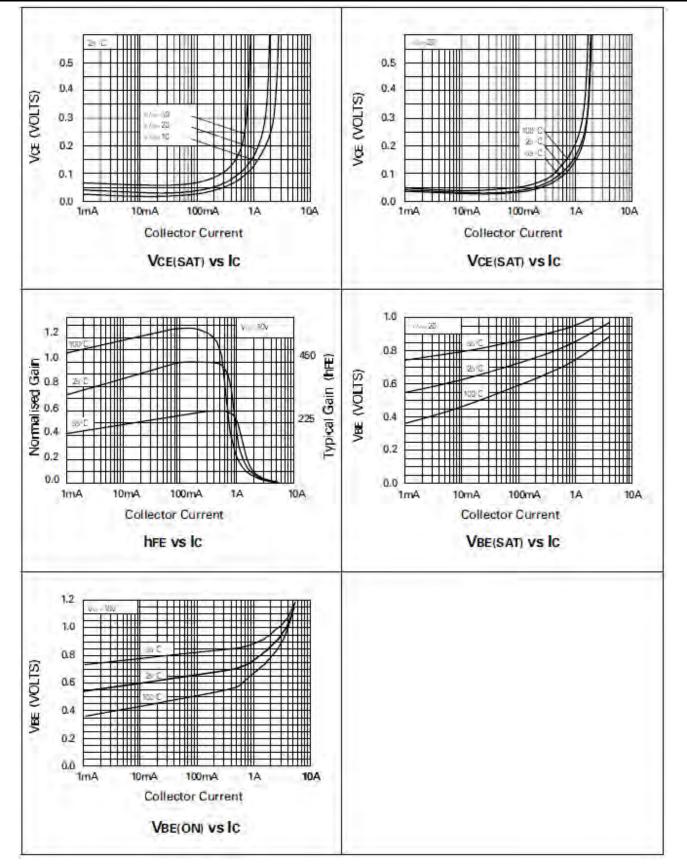
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	125	250	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 6)	BV _{CEO}	125	160	-	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	5	8.3	-	V	I _E = 100μA
Collector Cut-off Current	I _{СВО}	-	-	100	nA	V _{CB} = 100V
Emitter Cut-off Current	I _{EBO}	-	-	100	nA	$V_{EB} = 4V$
Collector Emitter Cut-off Current	I _{CES}	-	-	100	nA	$V_{CES} = 100V$
Static Forward Current Transfer Ratio (Note 6)	hFE	200 300 100 -	400 450 140 18		-	$\begin{split} I_{C} &= 10 \text{mA}, \ V_{CE} = 10 \text{V} \\ I_{C} &= 200 \text{mA}, \ V_{CE} = 10 \text{V} \\ I_{C} &= 1\text{A}, \ V_{CE} = 10 \text{V} \\ I_{C} &= 3\text{A}, \ V_{CE} = 10 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}		26 70 160 165	50 150 220 250	mV	$\begin{split} I_{C} &= 0.1A, \ I_{B} = 10 \text{mA} \\ I_{C} &= 0.5A, \ I_{B} = 1 \text{mA} \\ I_{C} &= 0.5A, \ I_{B} = 50 \text{mA} \\ I_{C} &= 1A, \ I_{B} = 50 \text{mA} \end{split}$
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}	-	0.85	1.0	V	$I_{C} = 1A, I_{B} = 50mA$
Base-Emitter Saturation Voltage (Note 6)	V _{BE(on)}	-	0.70	1.0	V	$I_{C} = 1A, V_{CE} = 10V$
Transition Frequency	fT	100	155	-	MHz	$I_{C} = 50$ mA, $V_{CE} = 10V$, f = 100MHz
Collector Output Capacitance	C _{obo}	-	7	15	pF	V _{CB} = 10V, f = 1MHz
Turn-On Time	t _(on)	-	60	-	ns	$V_{CC} = 50V, I_C = 0.5A,$
Turn-Off Time	t _(off)	-	1300	-	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$

6. Measured under pulsed conditions. Pulse width = 300 μ s. Duty cycle ≤ 2% Notes:





Typical Characteristics

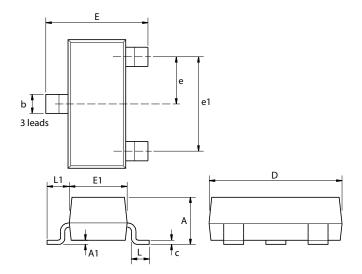


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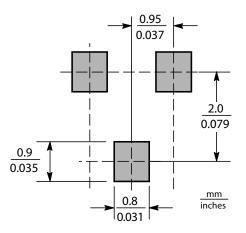
Package Outline Dimensions



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
А	-	1.12	-	0.044	e1	1.90 NOM		0.075 NOM	
A1	0.01	0.10	0.0004	0.004	E	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
с	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95 NOM		0.037	NOM	-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

Suggested Pad Layout







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